

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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TECHNICAL DATA

N-CHANNEL J-FET

Qualified per MIL-PRF-19500/431

Devices Qualified Level

2N4091 2N4092 2N4093

JANTX JANTXV

ABSOLUTE MAXIMUM RATINGS ($T_A = +25^{\circ}$ C unless otherwise noted)

Parameters / Test Conditions		Symbol	Value	Units
Gate-Source Voltage		V_{GS}	-40	V
Drain-Source Voltage		V_{DS}	40	V
Drain-Gate Voltage		$V_{ m DG}$	40	V
Gate Current		I_{G}	10	mAdc
Power Dissipation (1)	$T_A = +25^{\circ}C$	P_{T}	0.36	W
Operating Junction		$T_{\rm j}$	-65 to +175	°C
Operating Storage Temperature Range	·	T_{stg}	-65 to +200	°C

⁽¹⁾ Derate linearly 2.4 mW/ $^{\circ}$ C for $T_A > 25^{\circ}$ C.



*See appendix A for package outline

ELECTRICAL CHARACTERISTICS ($T_C = +25^{\circ}C$ unless otherwise noted)

PARAMETERS / TEST CONDIT	ΓIONS	Symbol	Min.	Max.	Units
Gate-Source Breakdown Voltage					
$V_{DS} = 0$, $I_{G} = -1.0 \mu\text{Adc}$		$V_{(BR)GSS}$	-40		Vdc
Gate Reverse Current					
$V_{DS} = 0$, $V_{GS} = -20$ Vdc		I_{GSS}		-0.1	ηΑ
Drain Current					
$V_{GS} = -12, V_{DS} = 20 \text{ Vdc}$	2N4091				
$V_{GS} = -8.0, V_{DS} = 20 \text{ Vdc}$	2N4092	$I_{D(off)}$		0.1	ηΑ
$V_{GS} = -6.0, V_{DS} = 20 \text{ Vdc}$	2N4093				-
Drain Current					
$V_{GS} = 0$, $V_{DS} = 20$ Vdc	2N4091	I_{DSS}	30		
	2N4092		15		mA
	2N4093		8.0		

2N4091, 2N4092, 2N4093 JAN SERIES

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}$ C unless otherwise noted) (con't)

PARAMETERS / TEST CONDITIONS		Symbol	Min.	Max.	Units	
Static Drain - Source On-State Resistance						
$V_{GS} = 0$, $I_{D} = 1.0$ mAdc		2N4091			30	
		2N4092	$r_{\rm DS(on)}$		50	Ω
		2N4093			80	
Drain - Source On-State V	oltage					
$V_{GS} = 0$, $I_{D} = 6.6$ mAdc		2N4091			0.2	
$V_{GS} = 0$, $I_{D} = 4.0$ mAdc		2N4092	$V_{DS(on)}$		0.2	Vdc
$V_{GS} = 0$, $I_D = 2.5$ mAdc		2N4093			0.2	
Small-Signal, Common-So	ource Reverse Trans	fer Capacitance				
$V_{GS} = 20 \text{ Vdc}, V_{DS} = 0, f = 1.0 \text{ MHz}$		C_{rss}		5.0	pF	
Small-Signal, Common-Source Short-Circuit Input Capacitance						
$V_{GS} = 0$, $V_{DS} = 20$ Vdc, $f = 1.0$ MHz		C_{iss}		16	pF	
Turn-On Delay Time	2N4091				15	
	2N4092		^t d _{on}		15	ηs
	2N4093	See Figure 3			15	
Rise Time	2N4091				10	
	2N4092	of MIL-PRF-	r r		20	ηs
	2N4093	19500/431			40	
Turn-Off Delay Time	2N4091				40	
	2N4092		^t d _{off}		60	ηs
	2N4093				80	